MODEL	DESCRIPTION
TPN1131A	120-volt, 60 Hz
TPN1135A	120/240-volt, 50 Hz

#### 1. DESCRIPTION

These power supplies produces various dc voltages which are used to operate a vacuum tube type high power (rf) amplifier for the transmitter and ac voltages which are used to drive the companion TPN1132A Low Voltage Power Supply. The voltages produced for operation of the power amplifier are: +1500 V dc for the plate circuit, +300 V dc for the screen circuit and -50 V dc for the tube bias voltage. The power supplies uses a constant voltage ferro-transformer to provide the basic operating voltages to the rectification circuits. This transformer maintains the output voltages within ±3% with a ±20% change in the input line voltage.

#### CAUTION

The input power must maintain an operating frequency to within ±3 Hz in order to keep within the regulation characteristics of the transformer. If the input power is obtained from a source other than a commercial power company, make sure that the operating frequency is kept within the 50 or 60 Hz ±3 Hz specification.

#### WARNING -- HIGH VOLTAGE

Extreme care must be exercised when servicing this equipment. Do not defeat interlock switches. It is a good practice to assume that HIGH VOLTAGES are present at all times, even after the acinput power is removed from the station.

The power supply contains an interlock protection circuit which prevents high voltages from being produced unless the station interlocks are enabled (closed). In addition, a power amplifier tube overcurrent protection circuit is provided which removes the screen voltage to the tubes in event of excessive plate current.

#### 2. FUNCTIONAL OPERATIONAL

The ac input to the power supply is routed through TB1 and F1 to T2. Two voltages are produced by half-wave rectification; the -50 V dc PA tube bias and the station safety interlock voltage. The interlock voltage is routed through the interlock switches and back to the power supply to energize K1. AC power is applied through the closed contacts of K1 to T1. The multiple winding secondary of T1 provides voltages to power the full-wave rectifier networks for the +1500 V dc and +300 V dc PA voltages, and to power the companion low voltage power supply.

The +300 V dc screen voltage is not developed until SCR gate Q51 is enabled when the station is keyed. This prevents the PA tubes from operating except when the station is keyed, thereby extending the useful life of the tubes.

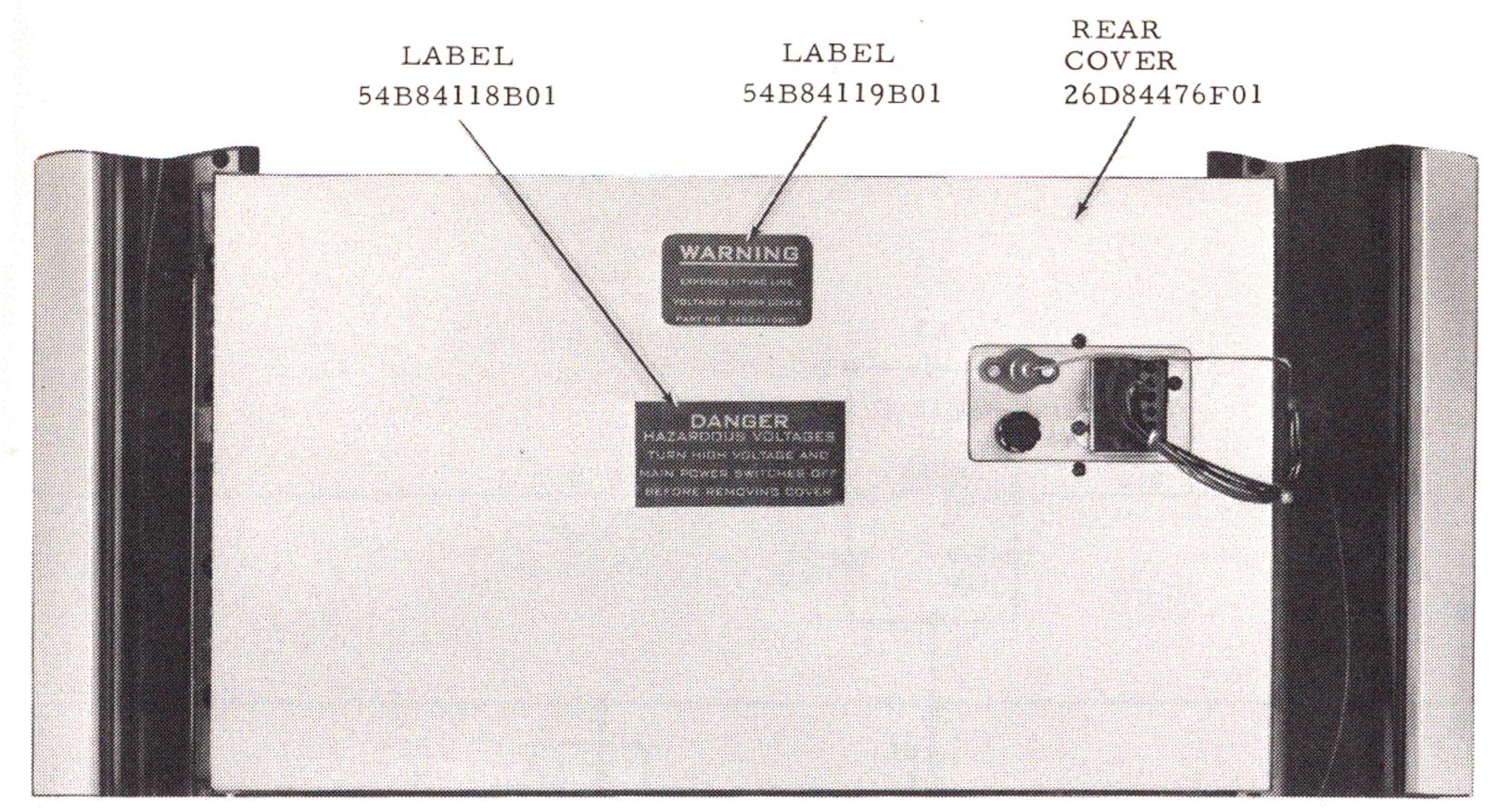
The screen voltage is enabled as follows. The transmitter turn-on switched A-function is applied through inverter Q57 to Schmitt Trigger Q56 and Q55. The Schmitt Trigger sets bistable multivibrator Q53 and Q54 so that Q53 is cut off and Q54 is turned on. The high voltage on the collector of Q53 causes switch Q52 to turn on and create a current path through T3. A positive voltage is applied to the gate of SCR Q51 which conducts and passes the +300 V dc screen voltage to the output filter.

If at any time the plate circuit of the PA tubes draws excessive current, the bias on Q54 decreases which causes Q54 to cut off and Q53 to turn on. This causes Q52 to turn off removing the gate voltage to SCR Q51 which stops conducting. Bistable multivibrator Q53 and Q54 is reset each time the station is keyed ensuring proper operation of the SCR enabling circuit.

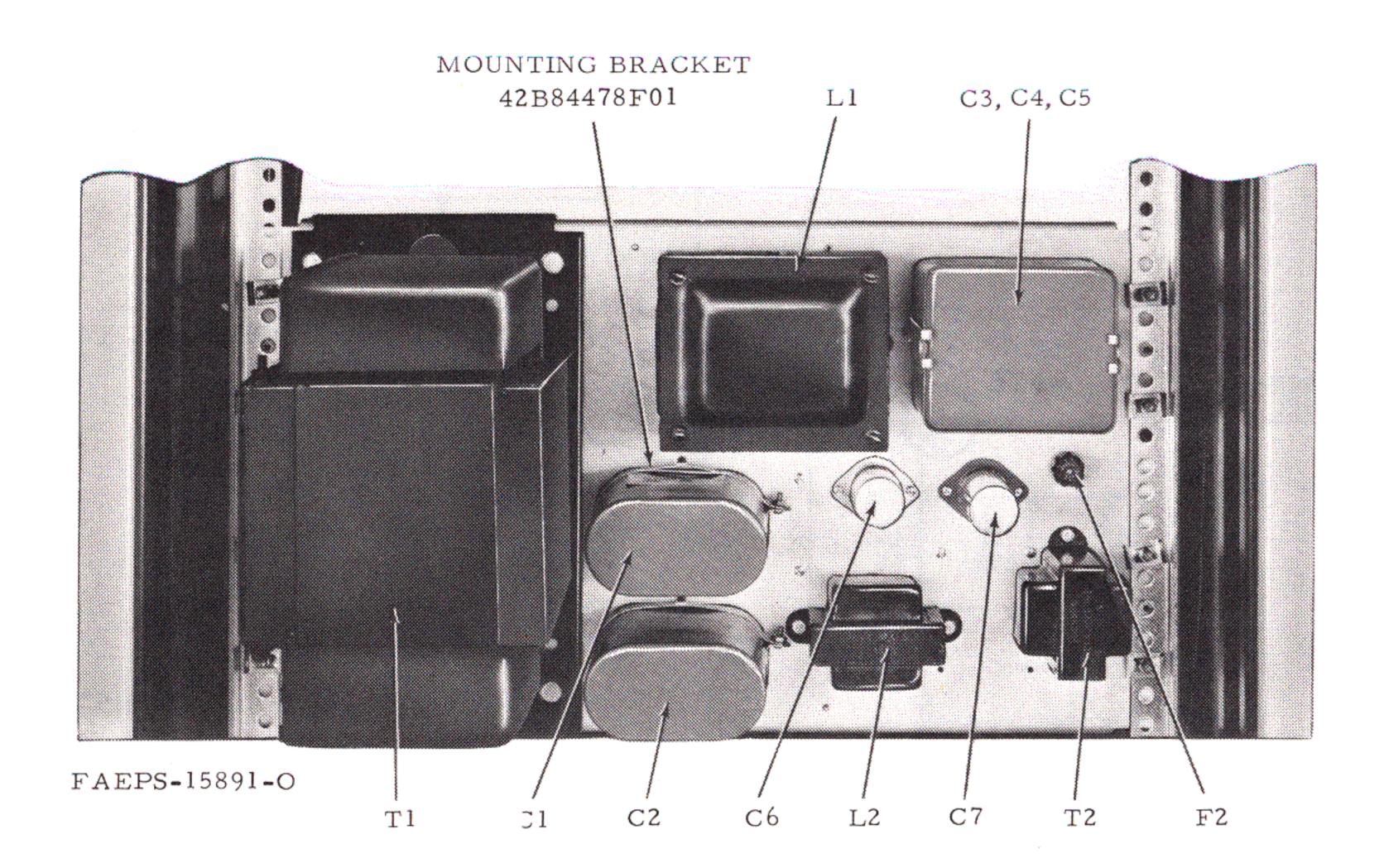


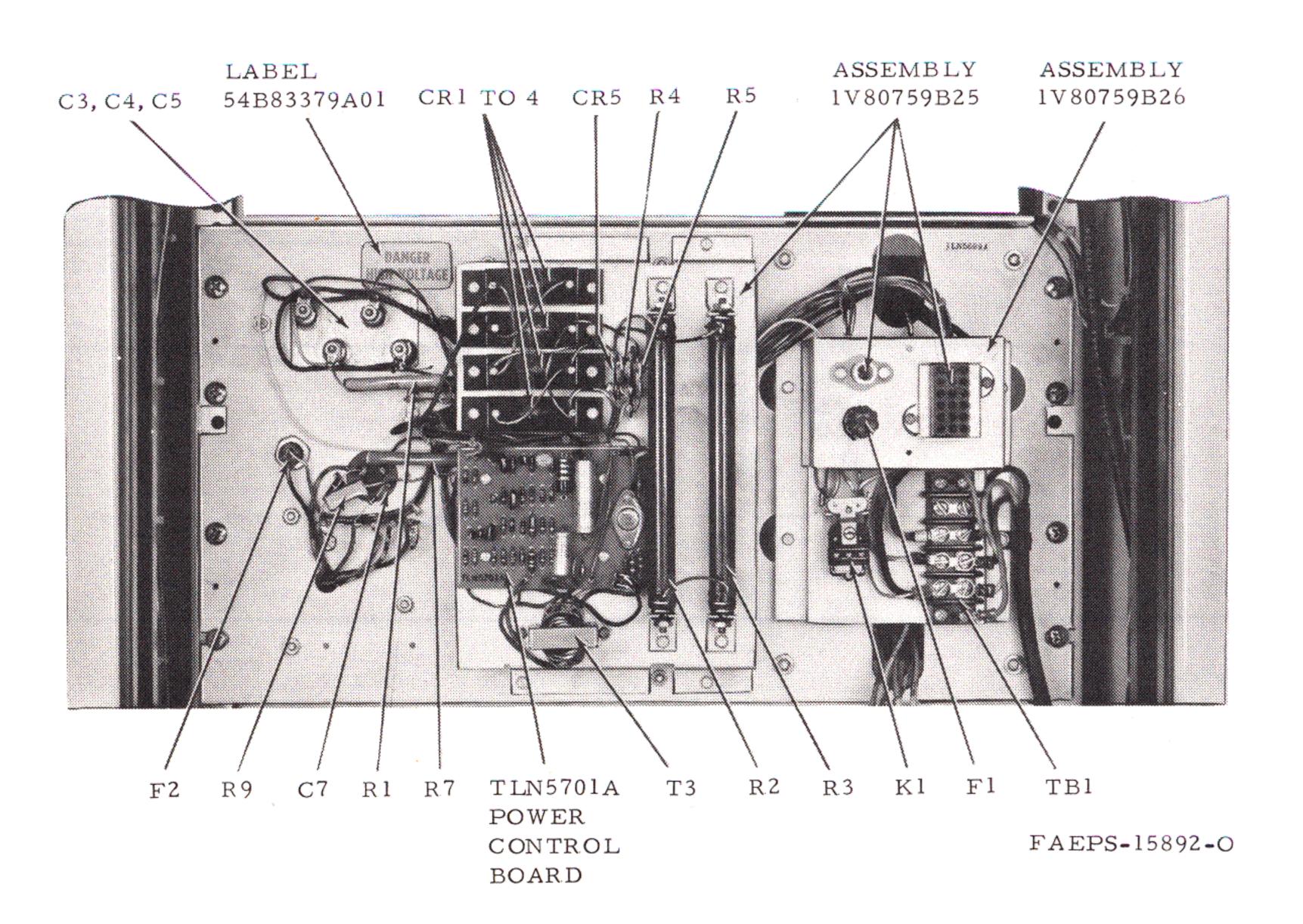
service publications

1301 E. Algonquin Road, Schaumburg, IL 60196



FAEPS-15890-O





REFERENCE MOTOROLA DESCRIPTION SYMBOL PART NO.

# PARTS LIST

TLN5701A Power Control Board (Both Models) PL-2861-B

I LIVOTOIA I OW	ver Control Doa	rd (Both Models) PL-2861-B
		CAPACITOR, fixed: uF ±10%
		unless otherwise stated
C51	23-83550B01	15 <b>-</b> 0 +33%, 60 V
C52, 53	21-847087	220; 300 V
C54	21-82428B36	.002; 200 V
C55	23-83210A19	500 -10+100%; 20 V
C56	23-82783B26	1.0; 35 V
		SEMICONDUCTOR DEVICE,
		diode: (SEE NOTE)
CR51 thru 54	48-82466H18	silicon
CR55, 56	48-82392B03	silicon
CR57	48-82466H18	silicon
CR58, 59, 60	48-82392B03	silicon
CR30, 37, 00	48-82466H18	silicon
CROI	40-024001110	SIIICOII
		TRANSISTOR: (SEE NOTE)
Q51	48-869349	silicon controlled diode; type
QSI	40-007347	1
053	10 040170	M9349
Q52	48-869170	NPN; type M9170
Q53, 54	48-869293	NPN; type M9293
Q55, 56	48-869570	NPN; type M9570
Q57	48-869643	PNP; type M9643
		RESISTOR, fixed: ±10%; 1/4 W
		unless otherwise stated
R51	6-10402C19	56; 1/2 W
R52	6-10402C33	220; 1/2 W
R53	6-10402C19	56; 1/2 W
R54	6-10401C75	12k
R55	6-10401C57	2.2k
R56,57	6-10401C73	10k
R58	6-10401C57	2.2k
R59	6-10402A53	$1.5k; \pm 5\%; 1/2 W$
R.60	6-10401A71	$8.2k \pm 5\%$
R61	6-10402A36	$300 \pm 5\%$ ; $1/2 W$
R62	6-10401A55	1.8k ±5%
R.63	6-10401C93	68k
R64,65	6-10401C59	2.7k
R66	6-10401C69	6.8k
R67	6-10401C61	3.3k
R68	6-10401C33	220
R69	6-10401C73	10k
R70	6-10401C75	12k
R71	6-10401C73	10k
R72	6-10401C65	4.7k
R73	6-10401C57	2.2k
R74	6-476116	270; 2 W
10.1-1	0-410110	
	- 14 A	

## NOTE:

For optimum performance, replacement diodes and transistors must be ordered by Motorola part number.

TKN6702A Cable, HV Power Supply (Both Models) PL-2862-A

THIT CASTO, III I OWEL BAPPLY (DOWN WIOGETS) I LI-LOUL-		
1	4-83783A01	INSULATOR, receptacle
2	9-82336A01	Terminal, female; ll req'd
4	2-10217A02	STRAP, cable harness; 14 req'd

REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION

TLN5699A Chassis, HV Power Supply (TPN1131A Model)
TPN6078A Chassis, HV Power Supply (TPN1135A Model) PL-2860-B

TPN6078A Chassis, HV Power Suppl	y(TPN1135A Model) PL-2860-
	APACITOR, fixed:
C1,2 8-84717G02 7	uF ±6%; 660 V (TLN5699A
	Chassis only)
or	*′
8-84717G03 8,	.5 uF ±6%; 660 V (TPN6078A
	Chassis only)
, , , ,	-section: 0.12 uF ±10%; 4400 V
0-02/441101 3	
	l uF ±10%; 4400 V
	1 uF ±10%; 3600 V
C6 23-82125B14 2	-section: 25 uF-10+50%;525 V
	25 uF-10+50%;525 V
C7 23-82125B13 2-	-section: 125 uF-10+100%;100 V
	125 uF-10+100%;100 V
i i	
l l si	EMICONDUCTOR DEVICE,
	iode: (SEE NOTE)
f 1 - 1	licon
	-diode potted assy.
CR6 thru 10   48-82466H18 si	llicon
]	
<u> </u>	USE, cartridge:
	OA
F2 65-817953 0.	.6A
	ELAY:
	2 V
K1 00-02015H02 12	s v
	OIL:
	part of TLN5704A)
	part of TLN5703A)
L2 25-82804H01 2.	.1H
[ [	
R	ESISTOR, fixed: ±10%:
	nless otherwise stated
R1 17-82476B06 4	±1%; 3 W
	5k; 75 W
	. 04 meg ±1%; 2W
	750 ±1%; 1/2 W
l	0k; 1/2 W
	0k; 7 W
R8 6-5583 47	7; 1 W
R9   17-83027H03 1.	.5k; 3 W
i . i	
Tr	RANSFORMER, power:
	art of TLN5703A and
	LN5704A)
	ri. BLK & BLK-WHT
1	ec. GRN & GRN-YEL
	ec. RED & RED-YEL
, ,	
	i. 1: BLK & BLK-WHT
	i. 2: BLU & BLU-WHT
	ec. 1: GRN & GRN-YEL
	c. 2: RED & RED-YEL
T3 25-83194C01 pr	i. RED & BLU
l se	c. GRN & YEL
	or ann a ree
	ec. BLK & BRN
se	ec. BLK & BRN
se BC	ec. BLK & BRN DARD, terminal:
TB2 31-82272B05 4-	c. BLK & BRN
TB2 31-82272B05 (TPN6078A)	ec. BLK & BRN  OARD, terminal;  dual terminals
TB2 31-82272B05 4- (TPN6078A) NON-REFERENC	cc. BLK & BRN  OARD, terminal: dual terminals  CED ITEMS
TB2 31-82272B05 4- (TPN6078A) NON-REFERENC 9-82083C03 F	ec. BLK & BRN  DARD, terminal: dual terminals  CED ITEMS  USEHOLDER; 2 req'd.
TB2 31-82272B05 4- (TPN6078A) NON-REFERENC 9-82083C03 F 27-84474F01 C	cc. BLK & BRN  DARD, terminal: dual terminals  CED ITEMS  USEHOLDER; 2 req'd.
TB2 31-82272B05 4- (TPN6078A)  NON-REFERENC 9-82083C03 F 27-84474F01 C 31-811350 T	cc. BLK & BRN  DARD, terminal: dual terminals  CED ITEMS  USEHOLDER; 2 req'd. CHASSIS ERMINAL BOARD; 4 terminal
TB2 31-82272B05 4- (TPN6078A)  NON-REFERENC 9-82083C03 F 27-84474F01 C 31-811350 T 30-82903H02 C	cc. BLK & BRN  DARD, terminal: dual terminals  CED ITEMS  USEHOLDER; 2 req'd.

NOT E:

For optimum performance, replacement diodes must be ordered by Motorola part number.

TLN5703A Transformer Kit (Used with 25-50 MHz Stations) (TPN1131A Model) PL-3025-A

Ll	25-84480F02	REACTOR: power filter choke; 15H ±10%; res 68 ohms ±10%
Tl	25-84507F01	TRANSFORMER, power: 95 to 145 V AC: pri: BLK, BLK
		sec No. 1: RED, RED-BLU w/ RED-YEL center tap sec No. 2: RED-WHT, RED-WHT
		sec No. 3: BLU, BLU w/BLU-YEL center tap
		sec No. 4: YEL, YEL w/YEL-GRN center tap

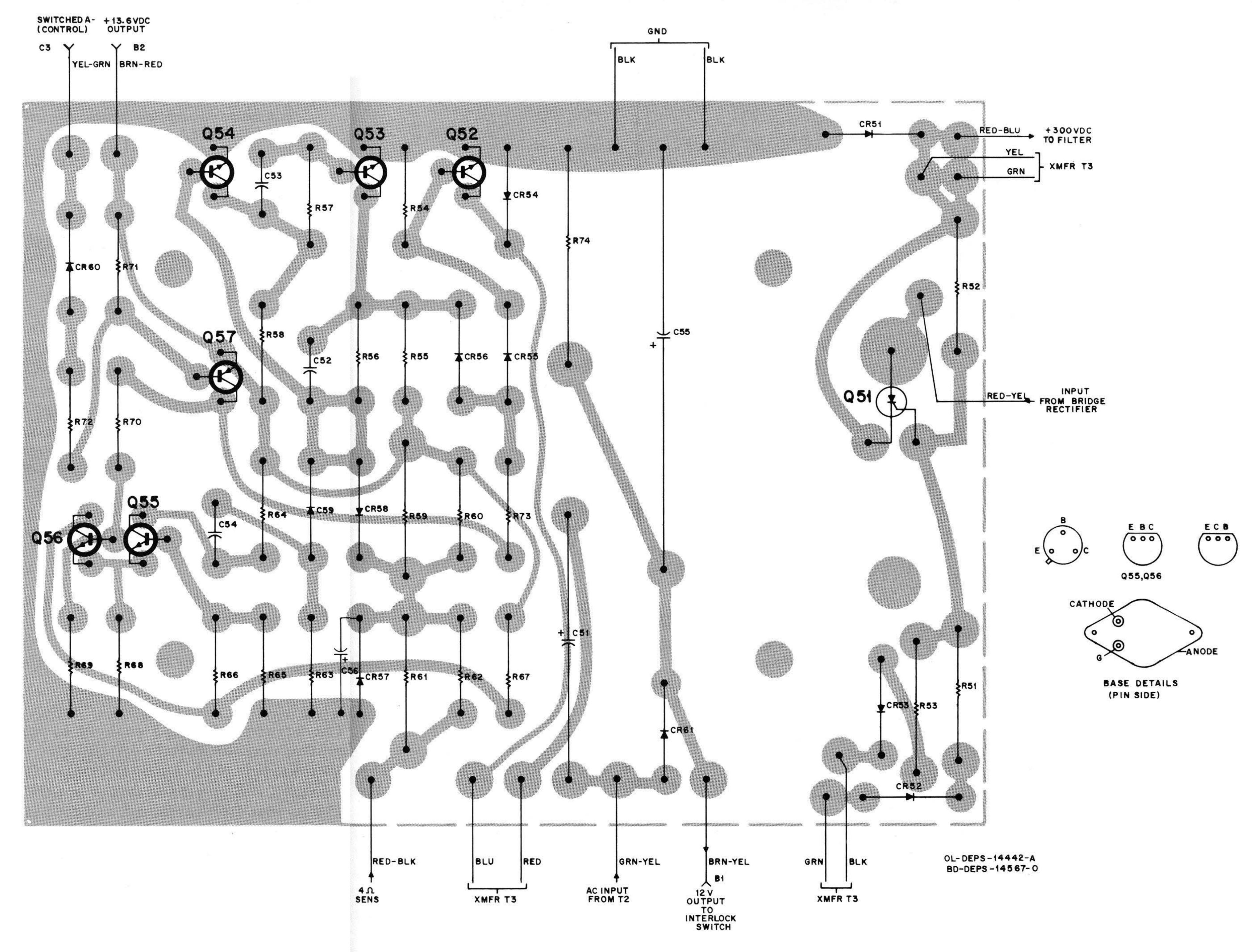
REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
01111100	1 7,111	

TLN5704A Transformer Kit (Used with 136-174 MHz Stations) (TPN1131A Model) PL-3026-A

(11111111111111111111111111111111111111	,	1 B-3020-A
L1	25-84480F01	REACTOR: power filter choke; 15H ±10%; res 76 ohms ±10%
TI	25-84507F01	TRANSFORMER, power: 95 to  145 V AC; pri: BLK, BLK sec No. 1: RED, RED-BLU w/RED-YEL center tap sec No. 2: RED-WHT, RED-WHT sec No. 3: BLU, BLU w/BLU- YEL center tap
		sec No. 4: YEL, YEL w/YEL- GRN center tap

TPN6079A Transformer Kit (Used with 136-174 MHz stations) (TPN1135A Model)

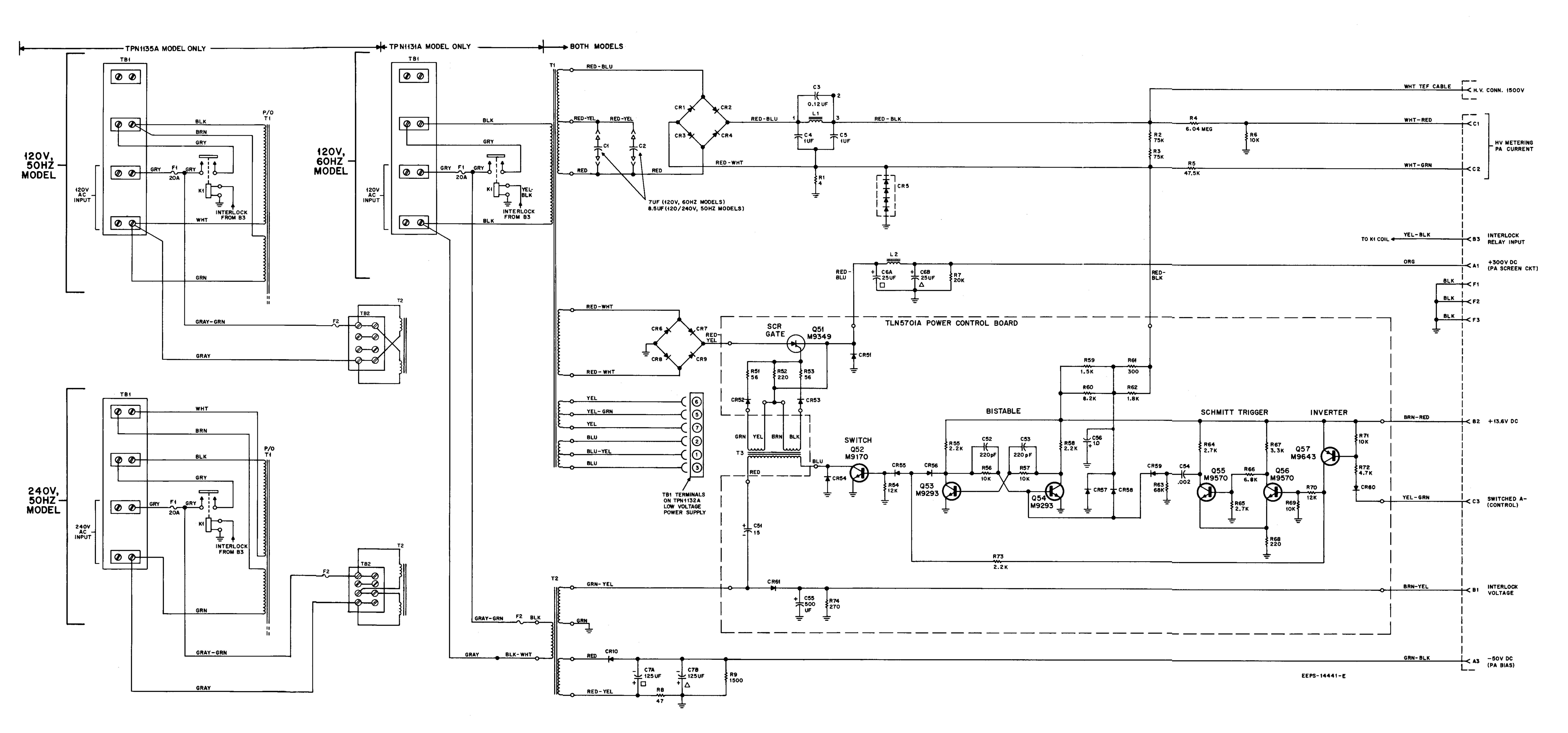
	PN1135A Model)	PL-3237-B
Ll	25-84480F01	REACTOR power filter choke; 15 H ±10%; res 76 ohms ±10%
TI	25-82476K01	TRANSFORMER, Power 120 or 240 V AC ±20%, 50 Hz pri #1 BLK, WHT pri #2 BRN, GRN sec No. 1: RED, RED-BLU w/RED-YEL center tap sec No. 2: RED-WHT, RED- WHT sec No. 3: BLU, BLU w/BLU- YEL center tap sec No. 4: YEL, YEL w/YEL- GRN center tap



## SHOWN FROM COMPONENT SIDE

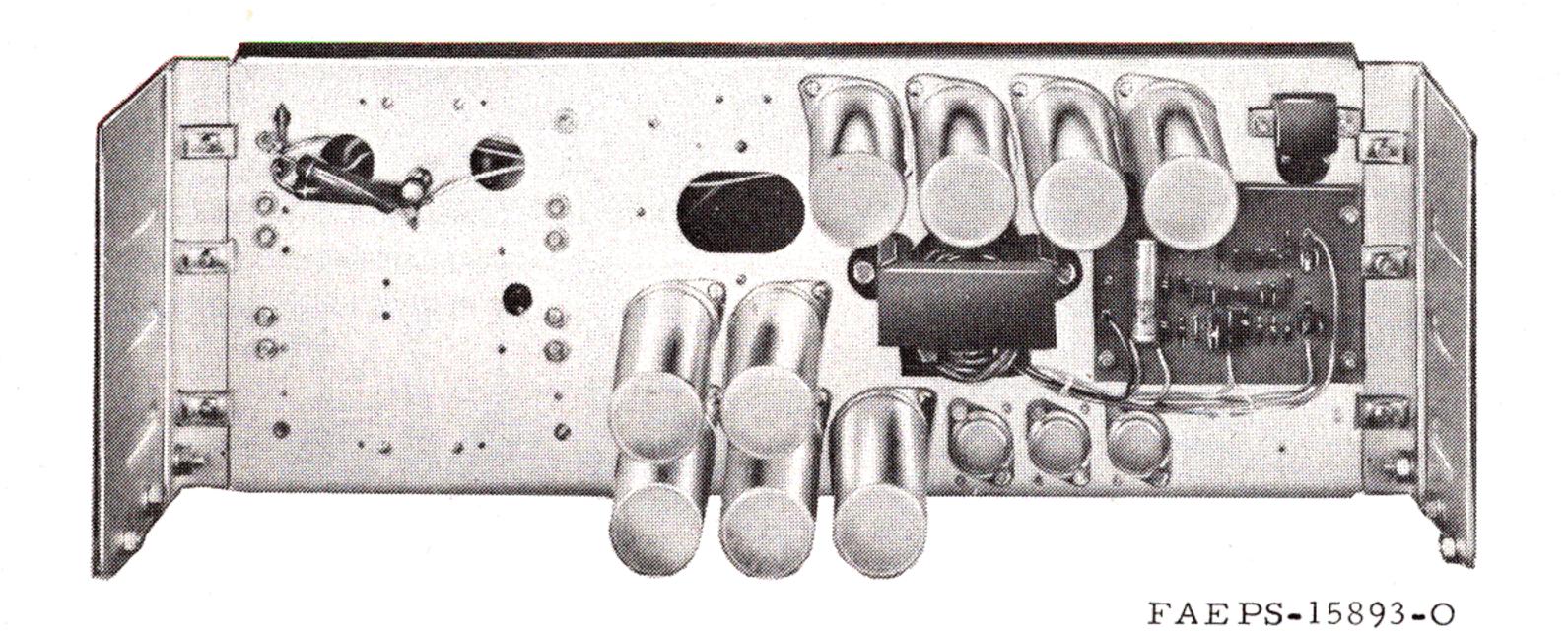
### MODEL TABLE

MODEL	DESCRIPTION	KITS INVOLVED
TPN1131A	120-Volt, 60 Hz Model	TLN5699A Chassis, HV Power Supply TLN5703A or TLN5704A Transformer Kit
TPN1135A	120/240-Volt, 50 Hz Model	TPN6078A Chassis, HV Power Supply TPN6079A Transformer Kit
BOTH MODELS		TLN5701A Power Control Board TKN6702A Cable, HV Power Supply



# LOW VOLTAGE POWER SUPPLY

MODEL TPN1132A





#### 1. DESCRIPTION

- 1.1 This power supply power supply provides the following output voltages:
  - --regulated 12 volts dc (adjustable) for the tube filaments of the high power rf amplifier.
  - --regulated 9.6 and 13.6 volts dc for operation of the solid state electronic circuitry contained within the station.
  - --filtered 13.6 volts dc for operation of the driver transistors on the exciter-driver chassis.
- 1.2 This low voltage power supply obtains its power from a companion high voltage power supply which provides a relatively constant input voltage regardless of primary power voltage changes. The low voltage power supply uses transistorized circuitry to provide a high degree of regulation for its three output voltages.

#### 2. THEORY OF OPERATION

#### 2.1 INPUT CIRCUITRY

Diodes CR1 and CR2 provide full wave rectification of the nominal 14.5 volt ac input applied to TB1-5, 6 and 7. The dc voltage is fed through a double-pie type LC filter and applied to the 12 volt regulator on the TLN5702A Filament Regulator Board, to the 9.6 volt regulator on the TLN5122A 9.6 V & 13.6 V Regulator Board, and to TB2-6 for the exciter-driver transistors. Diodes CR3 and CR4 provide full wave rectification of the nominal 18.5 volt ac input applied to TB1-1, 2 and 3. The dc voltage is capacitively filtered and applied to the 13.6 volt regulator on the TLN5122A 9.6 V & 13.6 V Regulator Board. Each regulator circuit is protected from drawing excessive current by a fuse in its input.

#### 2.2 9.6 V AND 13.6 V REGULATORS

#### 2.2.1 General

Except for the voltages involved, the operation of the 9.6 V and 13.6 V regulators is the same. The operation of the 9.6 V regulator is described in the following paragraphs. Refer to the schematic diagram while reading the circuit theory.

The 9.6 volt output is derived from a series regulator circuit that uses a higher level A+ as its source. An output voltage sensing circuit regulates the amount of current that is allowed to pass through the series regulator thus controlling the voltage across the load.

#### 2.2.2 Voltage Regulation

Transistors Ql, Q3 and Q4 form the voltage regulating circuit. Regulation is achieved by changing the amount of current allowed to flow through the base Q2. If the output voltage increases, the Q2 base current is decreased, and vice versa. The regulator output voltage is developed across R8 and R9. The voltage developed across R9 reflects all fluctuations of the output load voltage and is applied to the base of Q4. Since the emitter of Q4 is held to 8.2 volts by Zener diode VR1. Q4 conducts in response to the output load voltage fluctuations. When the output load voltage is 9.6 volts. O4 conducts at a certain level which fixes its collector voltage to a specific level. This voltage level determines the drive to the base of O3 and thus, also determines the drive to the base of O2. Ol is a constant current source for the collector of Q4 and the base of Q3. Current through Ql is held constant because of the voltage drop CR5 and CR6 which maintain a constant base to emitter bias voltage.

If the 9.6 volt output increases, the Q4 base voltage increases and Q4 conducts harder which causes its collector voltage to decrease. This causes O3 to conduct less and O3 collector draws less current. This decreases the amount of base current Q2 can draw, thus causing the emitter to collector impedance across Q2 to increase. The voltage dropped across Q2 increases, decreasing the output load voltage to normal. If the 9.6 volt output decreases, the above action reverses to bring the output voltage back up to the normal level. For the 9.6 V Regulator, the output voltage may range between 9.0 and 10.2 volts dc. For the 13.6 V Regulator, the output voltage may range between 12.9 and 14.5 volts dc.

#### 2.3 12 V FILAMENT REGULATOR

The 12 V Filament Regulator operates in a manner similar to that described for the 9.6 V and 13.6 V Regulators in the preceding paragraphs. This regulator uses an additional amplifier transistor (Q52) to increase the drive voltage available to driver stage Q53. In addition, Q53 is changed to a collector follower instead of an emitter follower, This reduces the minimum voltage drop permitted across series pass stage Q54. Q55 operates as a reference amplifier for the regulating circuitry and its operating point is adjustable with resistor R9.

#### 2.2.2 Voltage Regulation

Transistors Q1, Q3 and Q4 form the voltage regulating circuit. Regulation is achieved by changing the amount of current allowed to flow through the base Q2. If the output voltage increases, the Q2 base current is decreased, and vice versa. The regulator output voltage is developed across R8 and R9. The voltage developed across R9 reflects all fluctuations of the output load voltage and is applied to the base of Q4. Since the emitter of Q4 is held to 8.2 volts by Zener diode VR1, Q4 conducts in response to the output load voltage fluctuations. When the output load voltage is 9.6 volts. Q4 conducts at a certain level which fixes its collector voltage to a specific level. This voltage level determines the drive to the base of O3 and thus, also determines the drive to the base of Q2. Q1 is a constant current source for the collector of Q4 and the base of Q3. Current through Ql is held constant because of the voltage drop CR5 and CR6 which maintain a constant base to emitter bias voltage.

If the 9.6 volt output increases, the Q4 base voltage increases and Q4 conducts harder which causes its collector voltage to decrease. This causes O3 to conduct less and O3 collector draws less current. This decreases the amount of base current Q2 can draw, thus causing the emitter to collector impedance across Q2 to increase. The voltage dropped across Q2 increases, decreasing the output load voltage to normal. If the 9.6 volt output decreases, the above action reverses to bring the output voltage back up to the normal level. For the 9.6 V Regulator, the output voltage may range between 9.0 and 10.2 volts dc. For the 13.6 V Regulator, the output voltage may range between 12.9 and 14.5 volts dc.

#### 2.3 12 V FILAMENT REGULATOR

The 12 V Filament Regulator operates in a manner similar to that described for the 9.6 V and 13.6 V Regulators in the preceding paragraphs. This regulator uses an additional amplifier transistor (Q52) to increase the drive voltage available to driver stage Q53. In addition, Q53 is changed to a collector follower instead of an emitter follower, This reduces the minimum voltage drop permitted across series pass stage Q54. Q55 operates as a reference amplifier for the regulating circuitry and its operating point is adjustable with resistor R9.

#### 3. MAINTENANCE

Isolate malfunctions of this power supply following conventional troubleshooting procedures. Note that the ac input voltages to the power supply are not sinusoidal and thus, cannot be measured with a standard AC voltmeter. (The input waveforms will vary with the input and output load currents.) All voltage checks must be made where dc voltages are present.

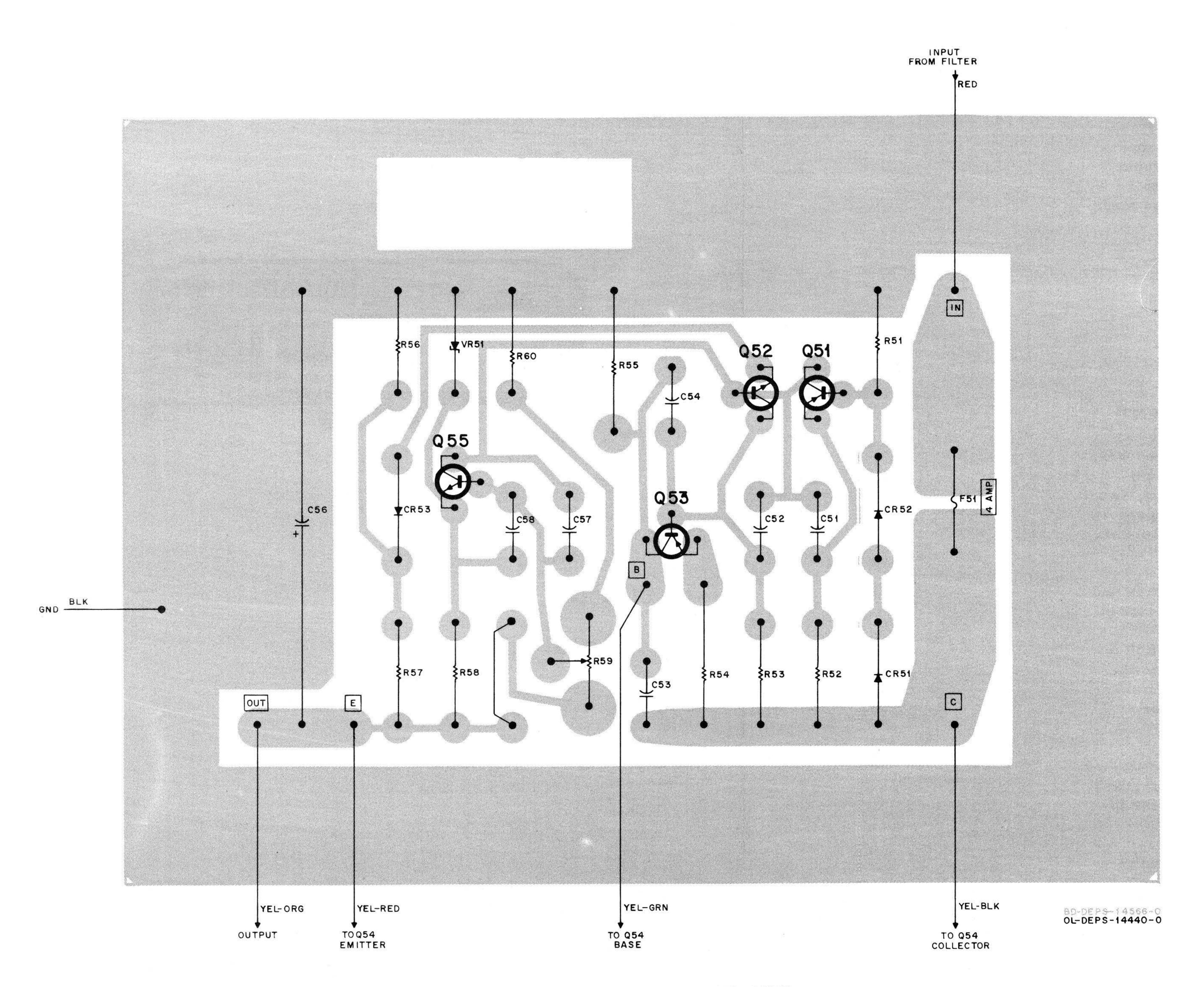
#### CAUTION

Turn the power to the station off and allow time for the capacitors to discharge through the bleeders resistors before attempting to replace components or repair this power supply.

#### 4. FILAMENT VOLTAGE ADJUSTMENT

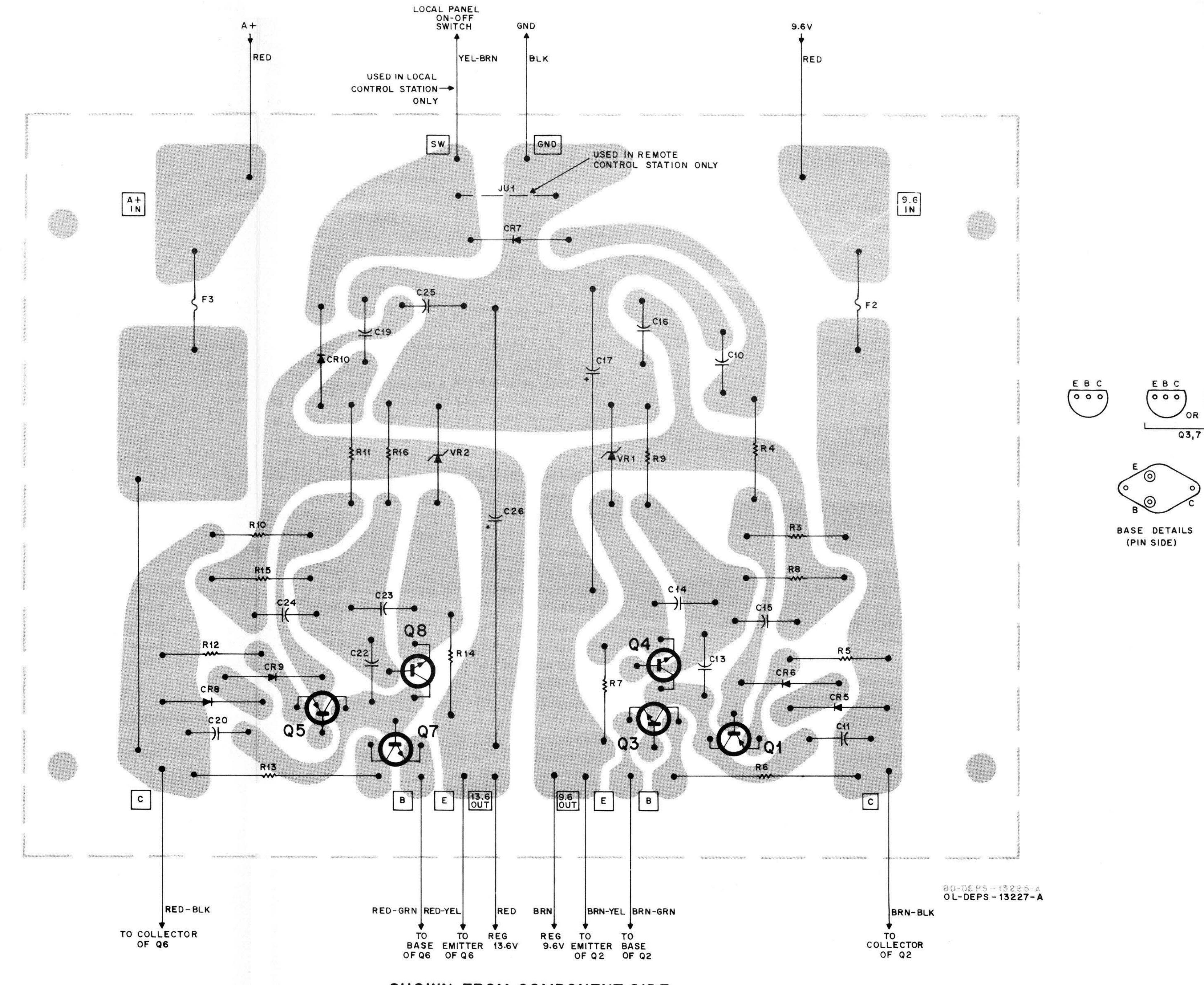
The filament voltage <u>must</u> be readjusted whenever the tubes within the high power rf amplifier are replaced. To make the adjustment, two controls are set while monitoring the filament voltage at the output terminals with a volt meter. Proceed as follows:

- STEP 1. Turn on the power to the station and make sure that all interlock switches are closed.
- STEP 2. Set filament voltage control R59 on the TLN5702A Filament Regulator Board to its midpoint position. Allow the power amplifier tube filaments to warm-up and stabilize for a minimum of two minutes.
- STEP 3. Connect the VOM across TB2-1 (+) and TB2-5 or -7 (-). Refer to the photograph on the back of the schematic diagram for the location of TB2.
- STEP 4. Set R59 to obtain 12.1 ±0.1 volts for low band (25-50 MHz) stations or 11.1 ±0.1 volts for high band (136-174 MHz) stations. Allow voltage to stabilize for one minute, after adjustment, before measurement.
- STEP 5. Connect the VOM across TB2-2 (+) and TB2-5 or -7 (-). Set the slider on R18 to obtain 6.0  $\pm$ 0.1 volts for low band stations or 5.5  $\pm$ 0.1 volts for high band stations. Allow voltage to stabilize for one minute, after adjustment, before measurement.



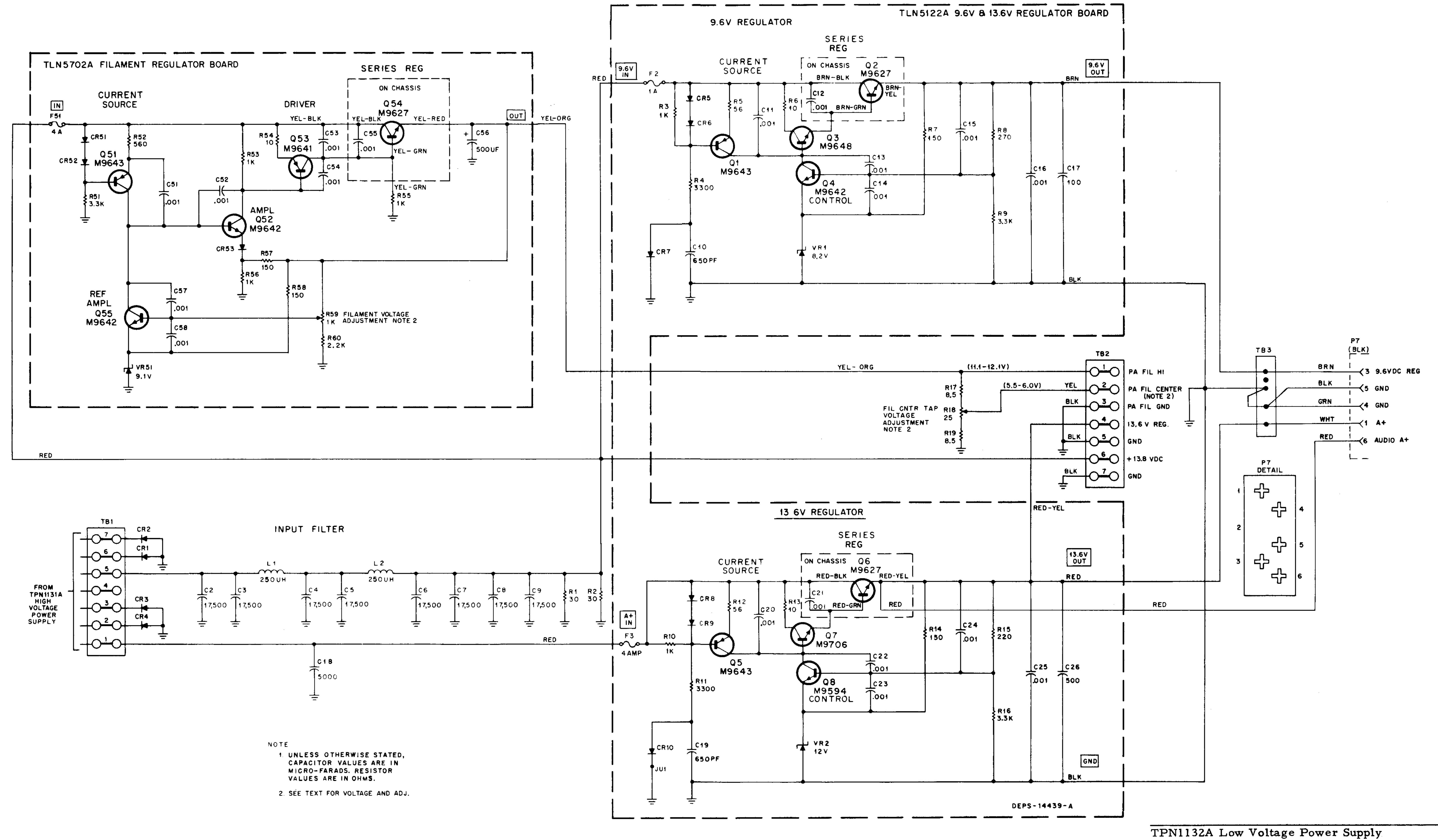
SHOWN FROM COMPONENT SIDE FILAMENT REGULATOR BOARD

TPN1132A Low Voltage Power Supply Schematic Diagram and Circuit Board Detail Motorola No. PEPS-15894-B (Sheet 1 of 2) 8/31/78-UP



SHOWN FROM COMPONENT SIDE 9.6V AND 13.6V REGULATOR BOARD

BASE DETAILS (PIN SIDE)



TPN113	2A MODEL	COMPLEMENT
MODELS	SUFFIX	DESCRIPTION
TKN6703A		CABLE LOW VOLTG
TLN5122A	1	9.6 V AND 13.6 V REGULATOR BOARD
TLN5700A		CHASSIS AND HARDWARE KIT
TLN5702A		FILAMENT REGULATOR BOARD

Schematic Diagram and Circuit Board Detail
Motorola No. PEPS-15894-B
(Sheet 2 of 2)
8/31/78-UP

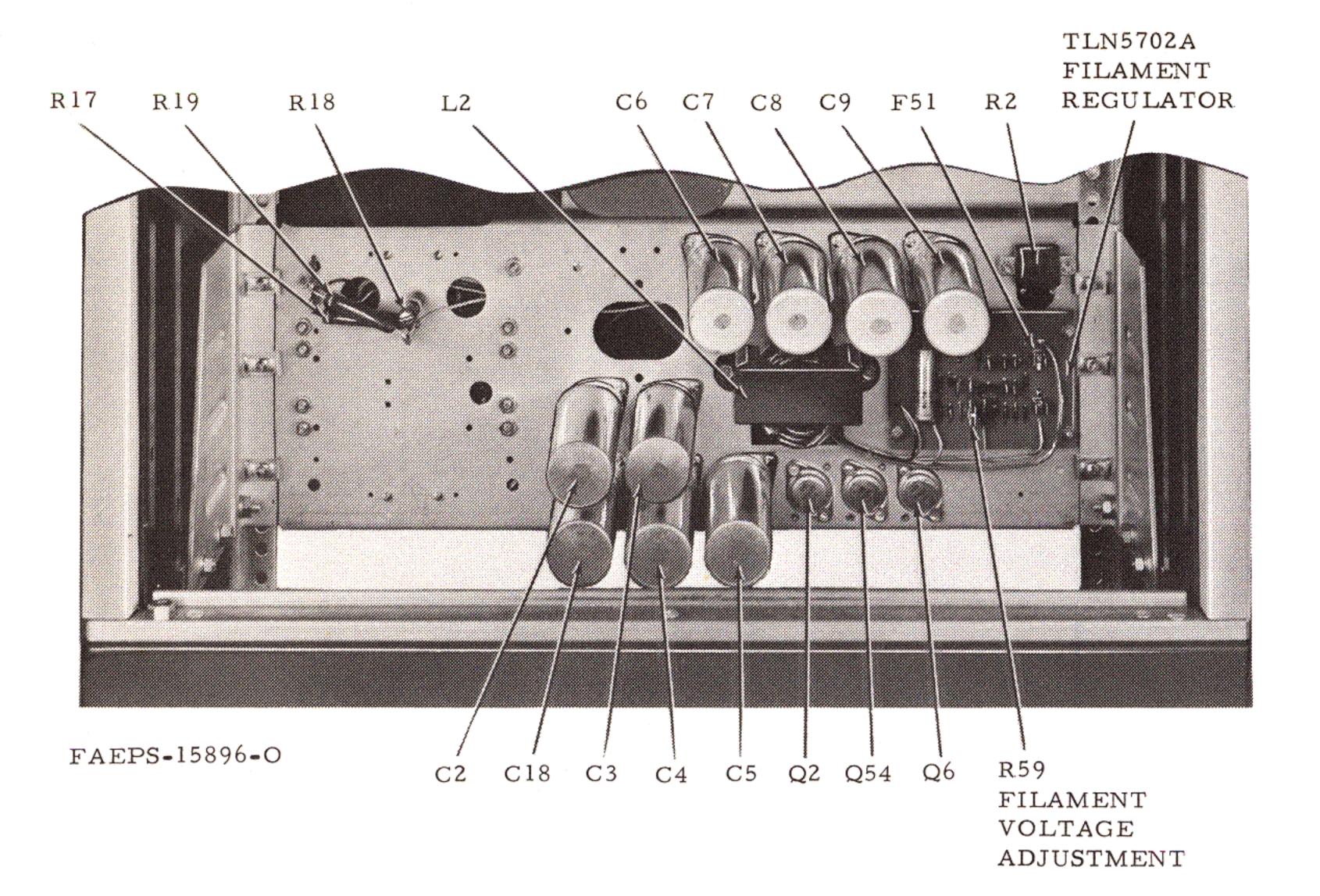


Figure 1. Chassis Mounted Parts

Identification (Front View)

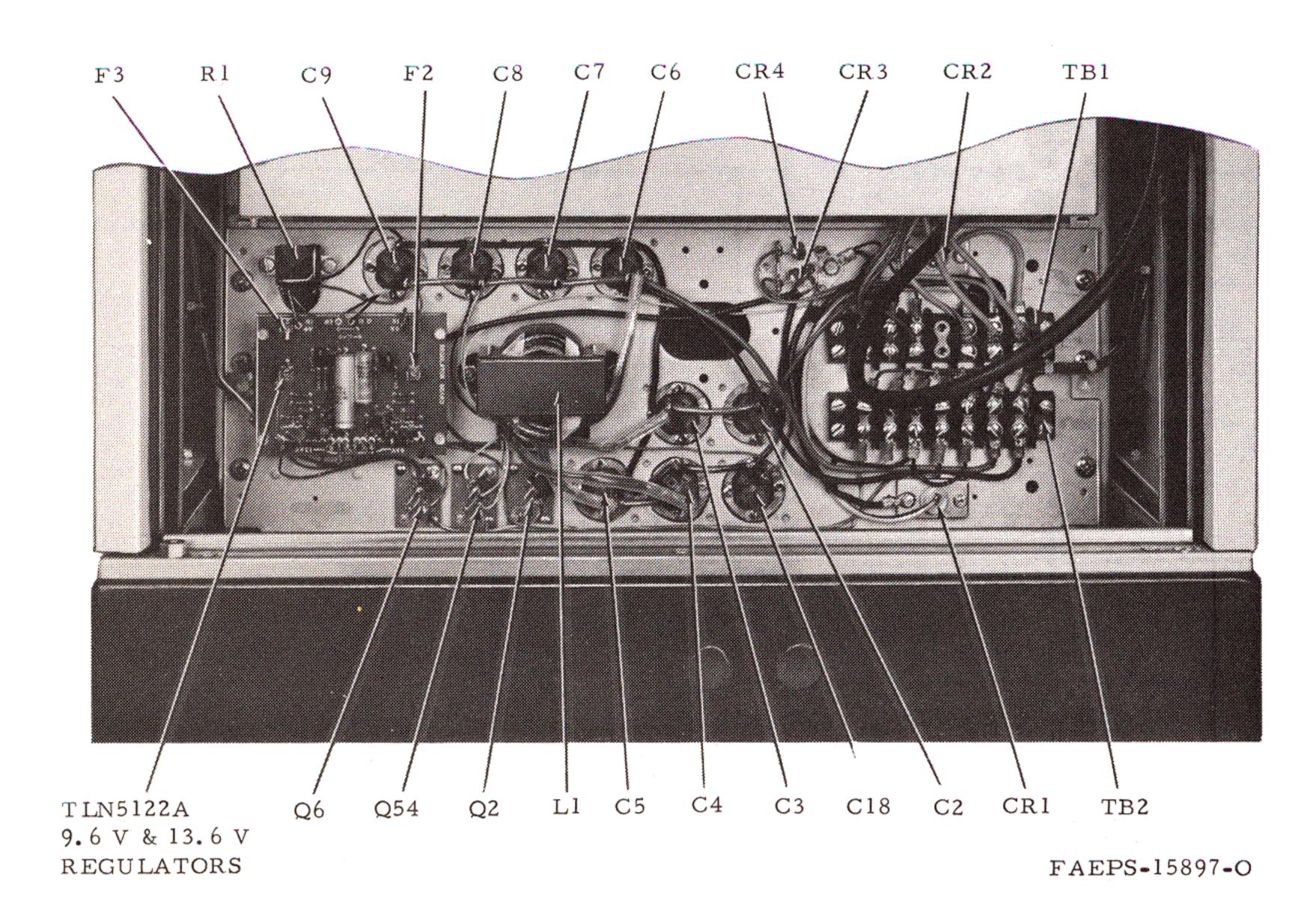


Figure 2. Chassis Mounted Parts
Identification (Rear View)

TPN1132A Low Voltage Power Supply Parts List and Parts Location Photographs Motorola No. PEPS-15895-A 8/31/78-UP

SYMBOL   PART NO.	REFERENCE SYMBOL	MOTOROLA PART NO.	DESCRIPTION
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#### **PARTS LIST**

TLN5122A Power Supply Board PL-2420-A CAPACITOR, fixed: uF ±10%; 100 V unless otherwise stated 21-848236 650 pF ±5%; 300 V C10 . 001 21-82187B20 CH C13 thru 16 21-82187B20 .001 C17 23-82601A25 100 -10+150%; 20 V C19 21-848236 650 pF ±5%; 300 V C20 21-82187B20 . 001 C22 thru 25 21-82187B20 .001 23-83210A19 500 -10+100%; 20 V SEMICONDUCTOR DEVICE, diode: (SEE NOTE) 48-83654 HOL CR5 thru 10 Silicon TRANSISTOR: (SEE NOTE) Qı 48-869643 PNP; type M9643 48-869648 NPN; type M9648 Q3 Q4 48-869642 NPN; type M9642 48-869643 PNP; type M9643 **O**5 48-869706 07 NPN; type M9706 08 48-869594 NPN; type M9594 RESISTOR, fixed: ±10%; 1/4 W unless otherwise stated R3 6-10401C49 lk 6-10401C61 3.3k R5 6-10401C19 56 6-488022 10; 1 W R6 R7 6-10401C29 150 6-10401A35 270 ±5% R8 RQ 6-10401A61 3.3k ±5% R10 6-10401C49 lk R 1 1 6-10401C61 3.3k R12 6-10401C19 56 R13 6-488022 10; 1 W R14 6-10401C29 150 R15 6-10401A33 220 ±5% R16 6-10401A61 3.3k ±5% SEMICONDUCTOR DEVICE, (SEE NOTE) VR I 48-82256 C08 Zener, 8.2 V VR2 48-82256C25 Zener, 12 V NON-REFERENCED ITEM

TLN5702A Filament Regulator

42-82690A01

PL-2856-O

CLIP, fuse; 4 req'd.

TLN5702A F	TLN5702A Filament Regulator PL-2856-O		
C51 thru 54 C56 C57, 58	21-82187B20 23-83210A19 21-82187B20	CAPACITOR, fixed: uF ±10%; 100 V unless otherwise stated .001 500+100-10% 20 V .001	
CR51, 52, 53	48-82392B03	DIODE: (SEE NOTE) silicon	
Q51 Q52 Q53 Q55	48-869643 48-869642 48-869641 48-869642	TRANSISTOR: (SEE NOTE) PNP; type M9643 NPN; type M9642 PNP; type M9641 NPN; type M9642	
R51 R52 R53 R54 R55,56 R57,58 R59	6-10401C61 6-10401C43 6-10402C49 6-10402C01 6-10401C49 6-10401C29 18-83083G04 48-82256C43 NON-REFERE	RESISTOR, fixed: ±10%; 1/4 W unless otherwise stated 3. 3k 560 1k; 1/2 W 10; 1/2 W 1k 150 variable: 1k ±30% VOLTAGE REGULATOR: (SEE NOTE) Zener; 9.1 V NCED ITEM	
	42-82690A01	CLIP, fuse; 2 req'd.	

REFERENCE MOTOROLA DESCRIPTION PART NO.

#### **PARTS LIST**

TLN5700A Chassis & Hardware Kit

PL-2859-0

	assis & nardwai	PL-2059-U		
C2 thru 9 C12 C18 C21 C55	23-83093G20 21-82187B14 23-82304B16 21-82187B14 21-82187B14	CAPACITOR, fixed: uF ±10%; 100 V unless otherwise stated 17500 +150-10%; 20 V .001 5000+150-10% 35 V .001 .001		
CR1,2 CR3,4	1-80739B59 48-82525G13	SEMICONDUCTOR DEVICE, diode: (SEE NOTE) silicon silicon		
F1 F2 F3	65-61688 65-52281 65-61688	FUSE, cartridge: 4A; 250 V 1A; 250 V 4A: 250 V		
L1,2	25-84514G01	COIL, choke: 250 uH		
Q2 Q6 Q54	48-869627 48-869627 48-869627	TRANSISTOR: (SEE NOTE) NPN; type M9627 NPN; type M9627 NPN; type M9627		
R1, 2 R17 R18 R19	17-83389G02 17-82291B36 17-851657 17-82291B36	RESISTOR, fixed: ±10%; 10 W unless otherwise stated 30 ±5%; 20 W 8.5 25 8.5		
NON-REFERENCED ITEMS				
	14-865854 15-84558F02 31-82596E02 42-10217A02 43-864364 43-83620H01 43-84510G01 9-84935D01 27-84135G02 31-118964 31-120365 31-490143 64-850015	INSULATOR, transistor; 3 req'd COVER, rear TERMINAL BOARD; 7 terminals STRAP, cable; 5 req'd SPACER, threaded; 4 req'd SPACER, plated; 4 req'd SPACER; 4 req'd SOCKET, transistor; 3 req'd CHASSIS, power supply TERMINAL STRIP, 4 terminal TERMINAL STRIP, 2 terminal TERMINAL STRIP, 2 terminal PLATE, cap. mtg.; 9 req'd		

#### NOTE:

For optimum performance, replacement diodes and transistors must be ordered by Motorola part number.

TKN6/U3A	able, Low Volta	age Power Supply	PL-2857-O
	9-84151B03 14-84590B01 42-10217A02		nnector

	PEPS-15895-A		
CHASSIS AND SUFFIX NO.	REF. Symbol	CHANGE	LOCATION
TLN5122A-1	Ω7	FROM 48-869648, M9648 TO 48-869706, M9706	13.6 V SERIES REGULATOR
	Q8	FROM 48-869642, M9642 TO 48-869594, M9594	